

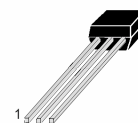
**HC144T****APPLICATIONS**

Switching Circuit , Interface Circuit.

**ABSOLUTE MAXIMUM RATINGS (  $T_a=25$  )**

$T_{stg}$	Storage Temperature.....	-55~150
$T_j$	Junction Temperature.....	150
$P_C$	Collector Dissipation.....	300mW
$V_{CBO}$	Collector-Base Voltage.....	50V
$V_{CEO}$	Collector-Emitter Voltage.....	50V
$V_{EBO}$	Emitter-Base Voltage.....	10V
$I_C$	Collector Current.....	100mA

TO-92S



- 1 Emitter , E
- 2 Collector,C
- 3 Base , B

**ELECTRICAL CHARACTERISTICS (  $T_a=25$  )**

Symbol	Characteristics	Min	Typ	Max	Unit	Test Conditions
$BV_{CBO}$	Collector-Base Breakdown Voltage	50			V	$I_C=10 \mu A, I_E=0$
$BV_{CEO}$	Collector-Emitter Breakdown Voltage	50			V	$I_C=0.1mA, I_B=0$
$BV_{EBO}$	Emitter-Base Breakdown Voltage	5			V	$I_E=50 \mu A, I_C=0$
$I_{CBO}$	Collector Cut-off Current			0.1	$\mu A$	$V_{CB}=40V, I_E=0$
$I_{EBO}$	Emitter Cut-off Current			0.1	$\mu A$	$V_{EB}=5V, I_C=0$
$H_{FE}$	DC Current Gain	100	250	600		$V_{CE}=5V, I_C=1mA$
$V_{CE(sat)}$	Collector- Emitter Saturation Voltage		0.1	0.3	V	$I_C=5mA, I_B=0.5mA$
$V_I (off)$	Input Off Voltage	0.4	0.55	0.8	V	$V_{CE}=5V, I_C=0.1mA$
$V_I (on)$	Input On Voltage	0.8	2.0	4.0	V	$V_{CE}=0.2V, I_C=5mA$
$R_I$	Input Resistor	33	47	61	Kohm	
$f_T$	Current Gain-Bandwidth Product		250		MHz	$V_{CE}=10V, I_C=5mA$
$C_{ob}$	Output Capacitance		5.5		pF	$V_{CB}=10V, f=1MHz$